



	CPC1981Y	Units
Blocking Voltage	1000	V _P
Load Current	0.18	A _{rms}
On-Resistance	18	Ω

Features

- Power SIP Package
- Handle Load Currents Up to 0.25A
- High Reliability
- No Moving Parts
- Low Drive Power Requirements (TTL/CMOS Compatible)
- Arc-Free With No Snubbing Circuits
- 2500V_{rms} Input/Output Isolation
- No EMI/RFI Generation
- Machine Insertable, Wave Solderable

Applications

- Industrial Controls
- Motor Control
- Robotics
- Medical Equipment—Patient/Equipment Isolation
- Instrumentation
 - Multiplexers
 - Data Acquisition
 - Electronic Switching
 - I/O Subsystems
 - Meters (Watt-Hour, Water, Gas)
- IC Equipment
- Home Appliances

Description

Clare and IXYS have combined to bring OptoMOS® technology, reliability and compact size to a new family of high power solid state relays. As part of that family, the CPC1981Y is a 1-Form-A solid state relay. The CPC1981Y employs optically coupled MOSFET technology to provide 2500V_{rms} of input to output isolation. The efficient MOSFET switches and photovoltaic die use Clare's patented OptoMOS architecture while the input is controlled by a highly efficient GaAlAs infrared LED. The combination of low on resistance and high load current handling capabilities makes the relay suitable for a variety of high performance switching applications.

Approvals

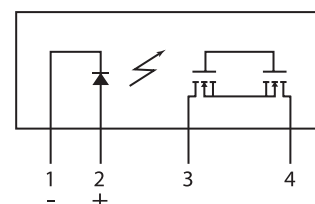
- UL recognized component: File # E69938
- Certified to: UL 508

Ordering Information

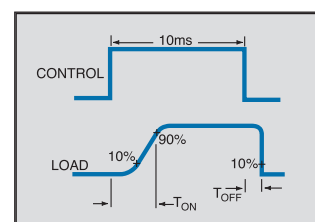
Part #	Description
CPC1981Y	Power SIP Package (25 per tube)

Pin Configuration

CPC1981Y Pinout



Switching Characteristics of Normally Open (Form A) Devices



Absolute Maximum Ratings (@ 25° C)

Parameter	Ratings	Units
Blocking Voltage	1000	V _P
Reverse Input Voltage	5	V
Input control Current	50	mA
Peak (10ms)	1	A
Input Power Dissipation ¹	150	mW
Isolation Voltage Input to Output	2500	V _{rms}
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

¹ Derate Linearly 3.33 mw / °C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Electrical Characteristics

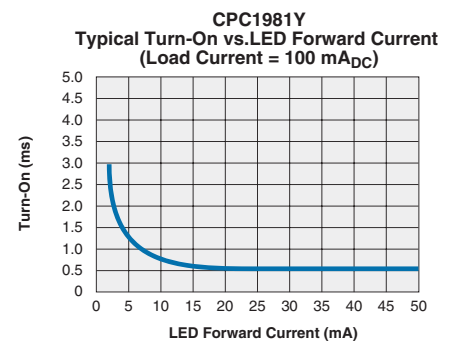
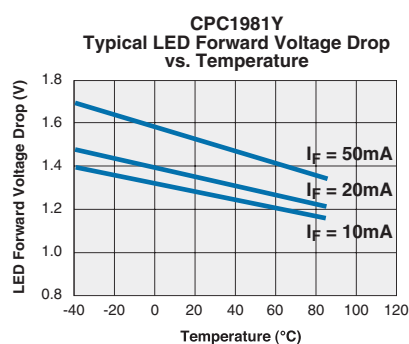
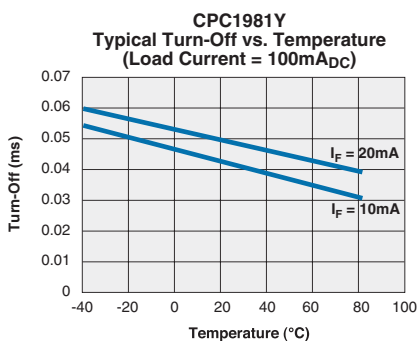
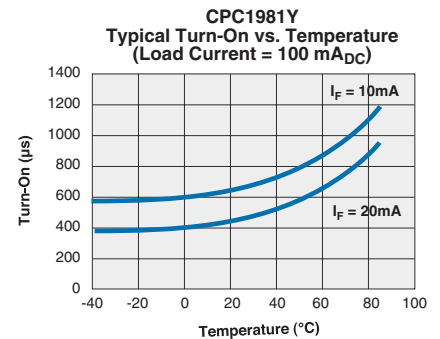
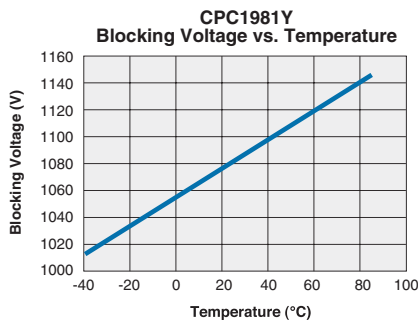
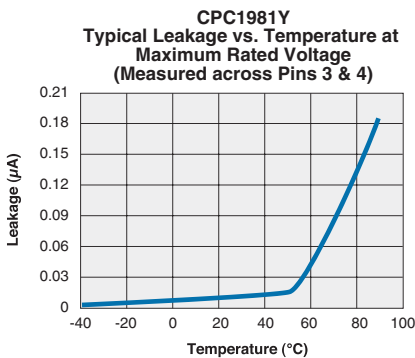
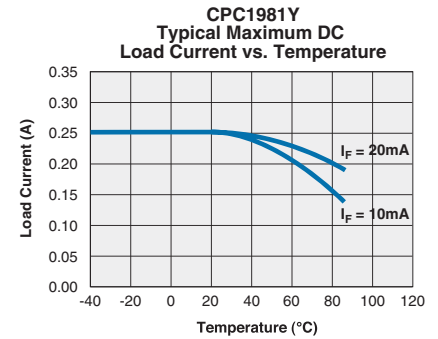
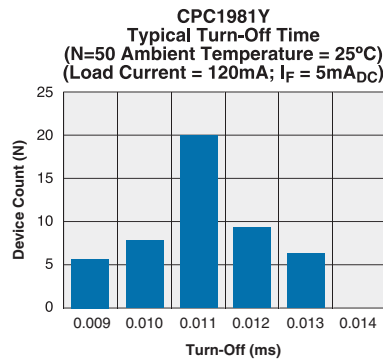
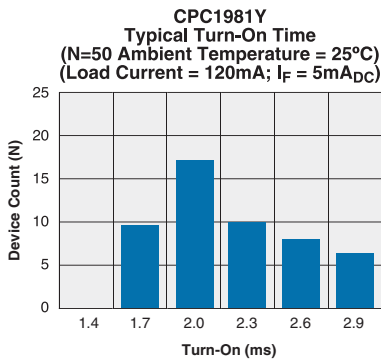
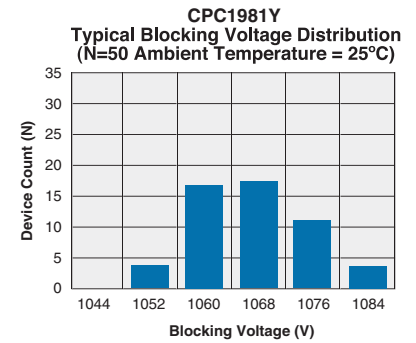
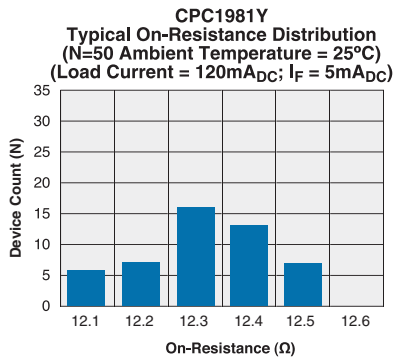
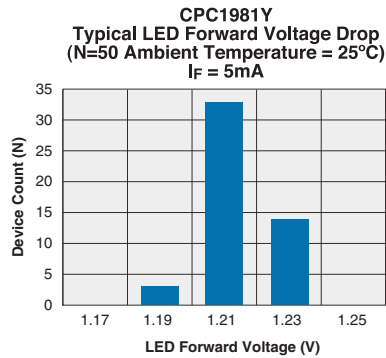
Parameter	Conditions	Symbol	Min	Typ	Max	Units
Output Characteristics @ 25°C						
Operating Voltage	-	V _L	5	-	600	V _{rms} or V _{DC}
Load Current, Continuous	free air	I _L	-	-	0.18	A _{rms}
Peak Load Current	10ms	I _{LPK}	-	-	1.1	A _{rms}
On-Resistance ¹	I _L =10mA	R _{ON}	-	12.3	18	Ω
Off-State Leakage Current	V _L =1000V	I _{LEAK}	-	-	1	μA
Switching Speeds	I _F =10mA, V _L =10V	T _{ON}	-	-	10	ms
Turn-On						
Turn-Off	I _F =10mA, V _L =10V	T _{OFF}	-	-	5	ms
Output Capacitance	30V, f=10MHz	C _{OUT}	-	31	-	pF
Input Characteristics @ 25°C						
Input Control Current	I _L =1.0A	I _F	10	-	-	mA
Input Dropout Current	-	I _F	0.6	-	-	mA
Input Voltage Drop	I _F =5mA	V _F	0.9	1.2	1.4	V
Reverse Input Current	V _R =5V	I _R	-	-	10	μA
Input/Output Characteristics @ 25°C						
Capacitance Input/Output	f=1MHz	C _{I/O}	-	2	-	pF

¹ Measurement taken within 1 second of on time.

Thermal Characteristics

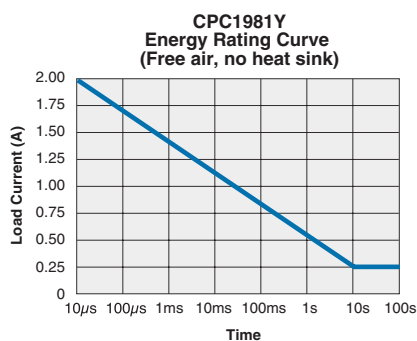
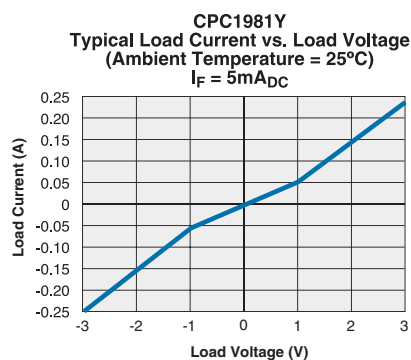
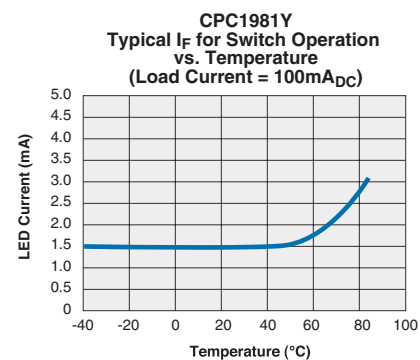
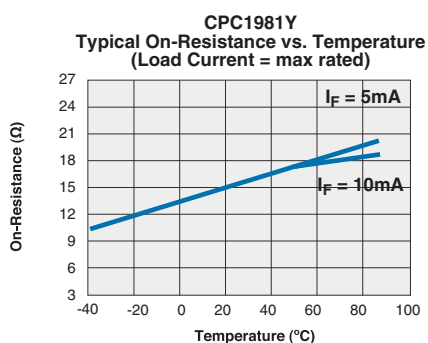
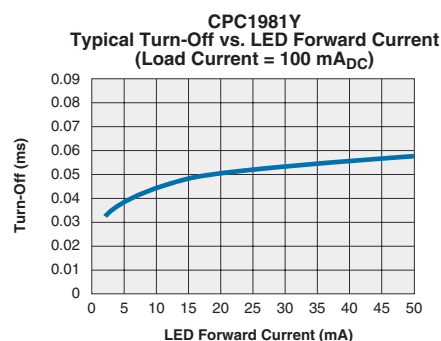
Parameter	Conditions	Symbol	Min	Typ	Max	Units
Thermal Resistance (junction to case)	-	R _{θJC}	-	1.5	-	°C/W

PERFORMANCE DATA*



*The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

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